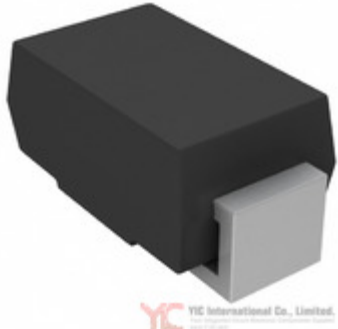

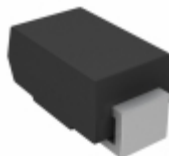
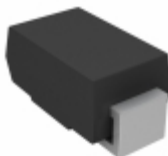

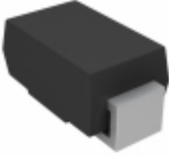
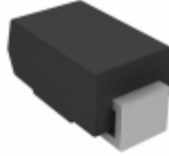
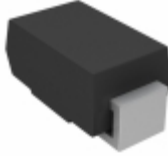
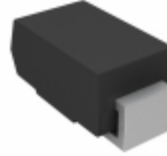
	<p>S1JHE3_A/I</p>
	<p>Hersteller-Teilenummer: S1JHE3_A/I</p> <p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p> <p>Teil der Beschreibung: DIODE GEN PURP 600V 1A DO214AC</p> <p>Datenblätter: 1.S1JHE3_A/I.pdf 2.S1JHE3_A/I.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 7500 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	S1JHE3_A/I
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	DIODE GEN PURP 600V 1A DO214AC
Kategorie	Diskrete Halbleiterprodukte > Dioden-Gleichrichter-
Teilstatus	7500 pcs Stock
detaillierte Beschreibung	Diode Standard 600V 1A Surface Mount DO-214AC
Serie	-
Befestigungsart	Surface Mount
Verpackung / Gehäuse	DO-214AC, SMA
Supplier Device-Gehäuse	DO-214AC (SMA)
Diodentyp	Standard
Strom - Richt (Io)	1A
Spannung - Forward (Vf) (Max) @ If	1.1V @ 1A
Strom - Sperrleckstrom @ Vr	1µA @ 600V
Spannung - Sperr (Vr) (max)	600V
Geschwindigkeit	Standard Recovery >500ns, > 200mA (Io)
Rückwärts-Erholzeit (Trr)	1.8µs
Betriebstemperatur - Anschluss	-55°C ~ 150°C
Kapazität @ Vr, F	12pF @ 4V, 1MHz
Verpackung	Tape & Reel (TR)
Basisteilenummer	S1J
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	S1JHE3_A/I-ND

S1JHE3_A/I ist neu im Original, Suche S1JHE3_A/I Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie S1JHE3_A/I Electro-Films (EFI) / Vishay mit Garantie und Vertrauen.
Anfrage S1JHE3_A/I: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>S1JL TSC S1JL TSC</p>	 <p>S1JHE3_A/H Electro-Films (EFI) / Vishay DIODE GEN PURP 600V 1A DO214AC</p>	 <p>S1JHE3/61T Vishay / Semiconductor - Diodes Division DIODE GEN PURP 600V 1A DO214AC</p>	 <p>S1JHR3G TSC (Taiwan Semiconductor) DIODE GEN PURP 600V 1A DO214AC</p>
 <p>S1JHM3/61T Vishay / Semiconductor - Diodes Division DIODE GEN PURP 600V 1A DO214AC</p>	 <p>S1JHM3/61T Electro-Films (EFI) / Vishay DIODE GEN PURP 600V 1A DO214AC</p>	 <p>S1JHE3/61T Electro-Films (EFI) / Vishay DIODE GEN PURP 600V 1A DO214AC</p>	 <p>S1JHE3_A/H Vishay / Semiconductor - Diodes Division DIODE GEN PURP 600V 1A DO214AC</p>

heiße Teile

Mehr

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LD061C123KAB2A	M25P32-VMF6TPA	MA2SD32008SO	P6SMB6.8AT/R	PSKH72/12IO1
D S-80819CLNB-B6ET2G	S1J-004HE3/5AT	S1J-13-F	S1J-13-G-72	S1J-6605E3/11
S1J-6605HE3/61T	S1J-6906/11T	S1J-6906E3/61T	S1J-6906HE3/61T	S1J-E3/11T
S1J-E3/5AT	S1J-E3/5AT	D S1J-E3/61T	S1J-E3/61T	S1J-M3/61T
S1J-M3/61T	D S1JA-E3/61T	S1JA-E3/61T	S1JB-13-F	S1JHE3/5AT
S1JHE3/5AT	S1JHE3/61T	S1JHE3/61T	S1JHE3_A/I	S4012DRP
SF800J22	SFH303FA-4	SI2325DS-T1-GE3	D SI4948BEY-T1-E3	SP3072EE
ST232ABD	STP95N04	TL7702ACP	UMK212B7223MD-T	XC6373A330PR

Contact us:Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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